

N-Channel 60 V (D-S) Super Junction Power MOSFET

PRODUCT SUMMARY						
V _{DS} (V)	$R_{DS(on)}(\Omega)$ $R_{DS(on)}(\Omega)$ $R_{DS(on)}(\Omega)$					
60	0.0015 at V _{GS} = 10 V	240				

FEATURES

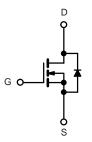
- 175 °C Junction Temperature
- DT-Trench Power MOSFET
- Material categorization:







Top View



N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)								
Parameter	Symbol	Limit	Unit					
Gate-Source Voltage	V_{GS}	± 20	V					
Continuous Drain Current (T _{.I} = 175 °C) ^b	T _C = 25 °C	I-	240					
Continuous Dialii Curient (1, = 175°C)	T _C = 100 °C	I _D	220 ^a					
Pulsed Drain Current	I _{DM}	960	Α					
Continuous Source Current (Diode Conduction)	I _S	240 ^a						
Avalanche Current	I _{AS}	220						
ingle Avalanche Energy (Duty Cycle ≤ 1 %) L = 0.1 mH		E _{AS}	614	mJ				
Maximum Power Dissipation	T _C = 25 °C	Pn	285	w				
Maximum i ower Dissipation	T _A = 25 °C	, р	2.5 ^{b, c}	VV				
Operating Junction and Storage Temperature Range	T _J , T _{stg}	- 55 to 175	°C					

THERMAL RESISTANCE RATINGS								
Parameter	Symbol	Typical	Maximum	Unit				
Marian and Innation to Ambient	t ≤ 10 sec	D	13	20	°C/W			
Maximum Junction-to-Ambient ^a	Steady State	R_{thJA}	40	50				
Maximum Junction-to-Case		R _{thJC}	0.55	1.0				

Notes:

- a. Package limited.
- b. Surface mounted on 1" x 1" FR4 board.
- c. $t \le 10 \text{ s}$.





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Parameter	Symbol	Test Conditions	Min.	Typ. ^a	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V_{DS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	60			V	
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1		3	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nΑ	
		V _{DS} = 48 V, V _{GS} = 0 V			1		
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 48 V, V _{GS} = 0 V, T _J = 125 °C			50	μΑ	
		V _{DS} = 48 V, V _{GS} = 0 V, T _J = 175 °C			250		
On-State Drain Current ^b	I _{D(on)}	V _{DS} = 5 V, V _{GS} = 10 V	240			Α	
		V _{GS} = 10 V, I _D = 20 A		0.0015	0.0020		
5 · 6 · 6 · 6 · 6 · 6	D	V _{GS} = 10 V, I _D = 20 A, T _J = 125 °C		0.0022	0.0032	Ω	
Drain-Source On-State Resistance ^b	R _{DS(on)}	V _{GS} = 10 V, I _D = 10 A, T _J = 175 °C		0.0029	0.0043		
Forward Transconductance ^b	9 _{fs}	V _{DS} = 48 V, I _D = 20 A		68		S	
Dynamic							
Input Capacitance	C _{iss}			11580			
Output Capacitance	C _{oss}	$V_{GS} = 0 \text{ V}, V_{DS} = 30 \text{ V}, f = 1 \text{ MHz}$		1346		pF	
Reverse Transfer Capacitance	C _{rss}			43			
Total Gate Charge ^c	Q_g			135	163		
Gate-Source Charge ^c	Q _{gs}	$V_{DS} = 30 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 20 \text{ A}$		51		nC	
Gate-Drain Charge ^c	Q_{gd}			20			
Turn-On Delay Time ^c	t _{d(on)}			31			
Rise Time ^c	t _r	$V_{DD} = 30 \text{ V, R}_{L} = 0.6 \Omega$		116		1	
Turn-Off Delay Time ^c	t _{d(off)}	$I_D \cong 20 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 2.5 \Omega$		81		ns	
Fall Time ^c	t _f			53			
Source-Drain Diode Ratings and Cha	racteristics (T _C = 25 °C)					
Pulsed Current	I _{SM}				960	Α	
Diode Forward Voltage	V_{SD}	$I_F = 20 \text{ A}, V_{GS} = 0 \text{ V}$		0.8	1.2	V	
Reverse Recovery Time	t _{rr}	I _F = 20 A, di/dt = 100 A/μs		75	150	ns	

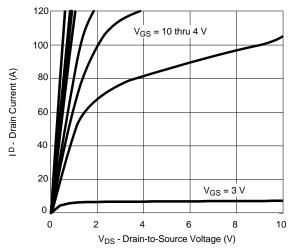
Notes:

- a. For design aid only; not subject to production testing.
- b. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- c. Independent of operating temperature.

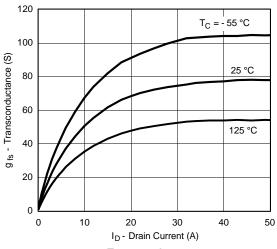
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



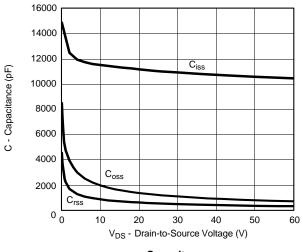
TYPICAL CHARACTERISTICS (25 °C unless noted)



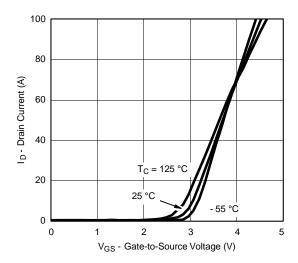
Output Characteristics



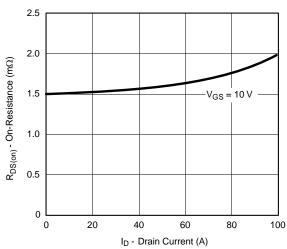
Transconductance



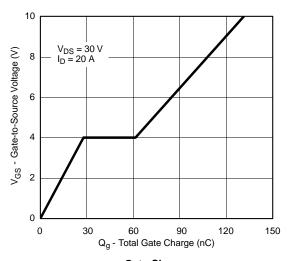
Capacitance



Transfer Characteristics



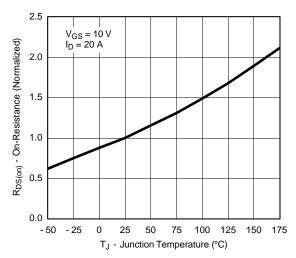
On-Resistance vs. Drain Current



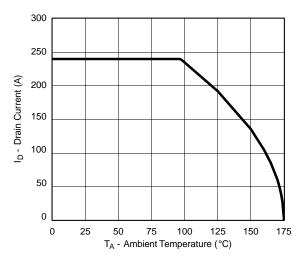
Gate Charge



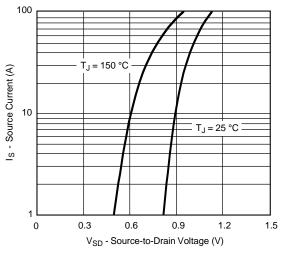
TYPICAL CHARACTERISTICS (25 °C unless noted)



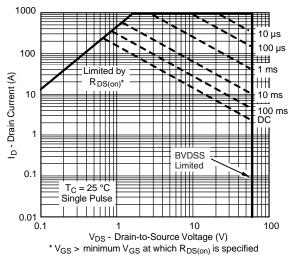
On-Resistance vs. Junction Temperature



Maximum Drain Current vs. Ambient Temperature



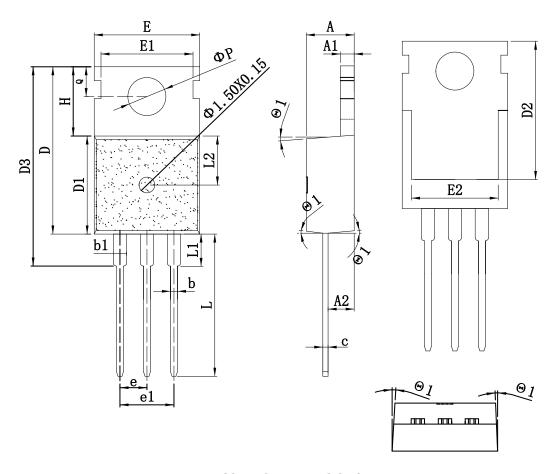
Source-Drain Diode Forward Voltage



Safe Operating Area



TO-220_3L-A PACKAGE OUTLINE

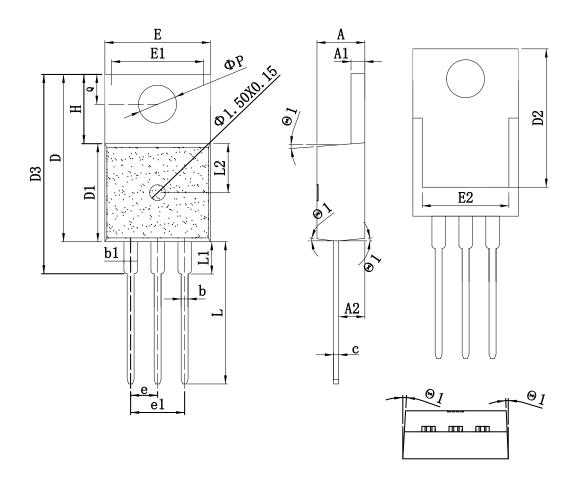


COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)

SYMBOL	mm			SYMBOL	mm			
STWIBOL	MIN	TYP	MAX	SIMBOL	MIN	TYP	MAX	
A	4.15	4.50	4.80	E1	8.25	8.70	9.15	
A1	1.15	1.30	1.50	E2	7.20	8.00	8.80	
A2	2.10	2.40	2.65	e	2.38	2.54	2.74	
b	0.65	0.80	1.00	e1	5.08REF			
b1	1.10	1.33	1.80	Н	6.20	6.50	6.90	
c	0.35	0.50	0.65	L	12.75	13.28	13.70	
D	14.25	15.75	16.15	L1	-	-	3.50	
D1	8.70	9.20	9.60	L2	2.30	4.65	7.00	
D2	12.30	13.10	13.85	φP	3.40	3.65	3.85	
D3	16.20	18.80	20.60	Q	2.50	2.80	3.00	
Е	8.68	10.02	11.00	θ	2°	-	7°	



TO-220_3L-B PACKAGE OUTLINE



COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)

SYMBOL	mm			SYMBOL	mm			
SIMBOL	MIN	TYP	MAX	SIMBOL	MIN	TYP	MAX	
A	4.15	4.50	4.80	E1	8.25	8.70	9.15	
A1	1.15	1.30	1.50	E2	7.20	8.00	8.80	
A2	2.10	2.40	2.65	e	2.38	2.54	2.74	
b	0.65	0.80	1.00	e1	5.08REF			
b1	1.10	1.33	1.80	Н	6.20	6.50	6.90	
С	0.35	0.50	0.65	L	12.75	13.28	13.70	
D	14.25	15.75	16.15	L1	-	-	3.50	
D1	8.70	9.20	9.60	L2	2.30	4.65	7.00	
D2	12.30	13.10	13.85	φP	3.40	3.65	3.85	
D3	16.20	18.80	20.60	Q	2.50	2.80	3.00	
Е	8.68	10.02	11.00	θ	2°	-	7°	





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